

Features

- Frequency: 8~12GHz
- RMS of Attenuation Accuracy: 0.5dB
- Insertion Loss: 3.8dB
- Positive Voltage Control
- Die Size: 1.79mm×1.25mm×0.1mm

Typical Applications

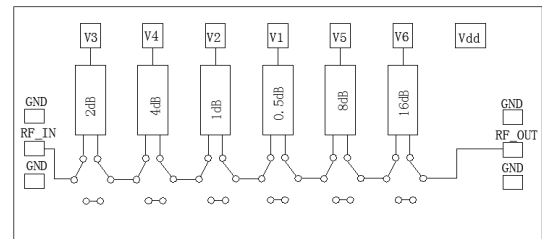
- EW
- Cellular Infrastructure
- SATCOM
- Beamforming Modules
- Test Equipment and Sensors

General Description

XT3403 is a broadband 6-bit GaAs digital attenuator MMIC chip. Covering 8 to 12GHz, the insertion loss is less than 3.8 dB typically. The attenuator bit values are 0.5dB, 1dB, 2dB, 4dB, 8dB and 16dB for a total attenuation of 31.5dB. Three TTL 0/+5V inputs are used to select each attenuation state.

The chip offers full passivation for increased reliability and moisture protection.

Functional Diagram



Electrical Performance ($T_A = +25^\circ\text{C}$, $V_D = -5\text{V}$, Control Voltage = 0/+5V, $Z_0 = 50\Omega$)

Parameter	Min.	Typ.	Max.	Units
Frequency	8~12			GHz
Input VSWR	—	1.3	—	:1
Output VSWR	—	1.3	—	:1
Insertion Loss	—	-3.8	—	dB
A_{TT} -Phase Error	-2	—	2.5	°
Attenuation Accuracy	-0.5	—	1	dB
RMS of Attenuation Accuracy	—	0.5	—	dB

Truth Table (0 : 0V , 1 : +5V)

Attenuation	V1	V2	V3	V4	V5	V6
REF	0	0	0	0	0	0
0.5dB	1	0	0	0	0	0
1dB	0	1	0	0	0	0
2dB	0	0	1	0	0	0
4dB	0	0	0	1	0	0
8dB	0	0	0	0	1	0
16dB	0	0	0	0	0	1
31.5dB	1	1	1	1	1	1

Absolute Maximum Ratings

Maximum Input Power	+23dBm	Operating Temperature	-55°C ~ +85°C
Maximum Input Voltage	-8V	Storage Temperature	-65°C ~ +150°C

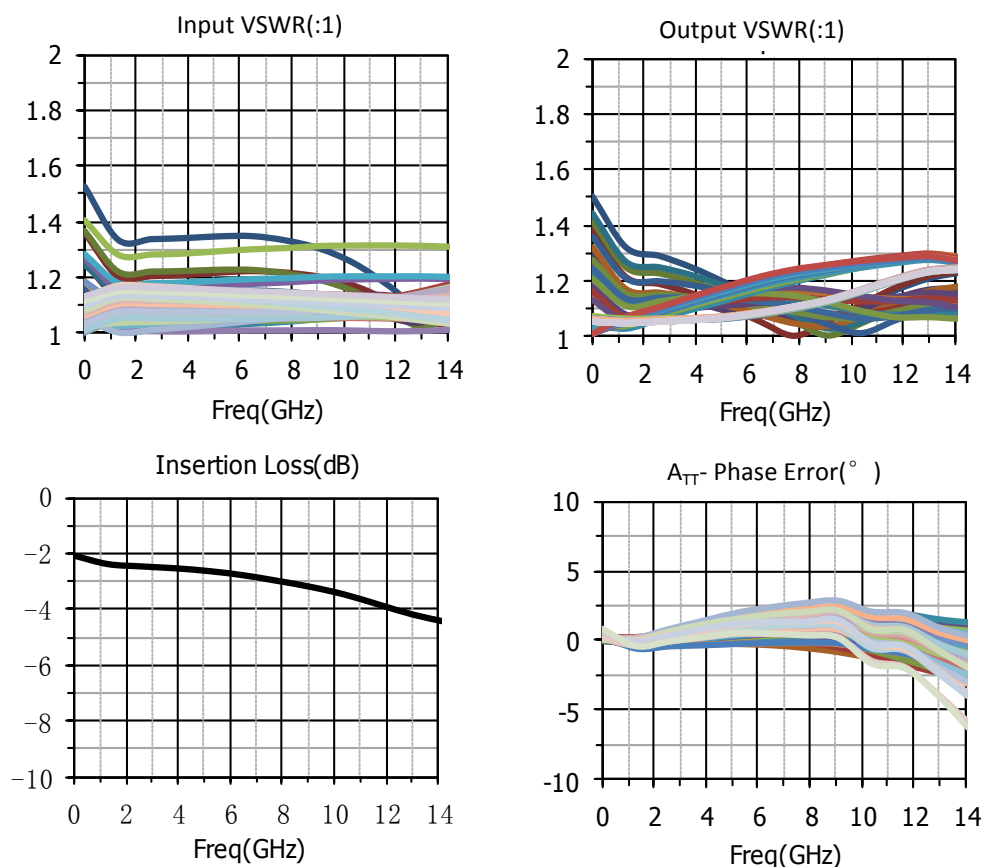
Control Voltage

State	Bias
Low	0~0.5V
High	4.5~5.5V

Power Supply

V _D	I _D
-5V	8mA

Typical Performance Curve

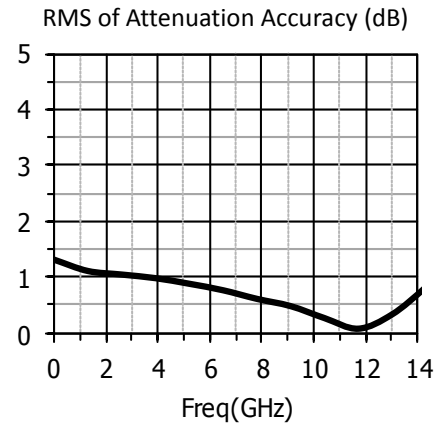
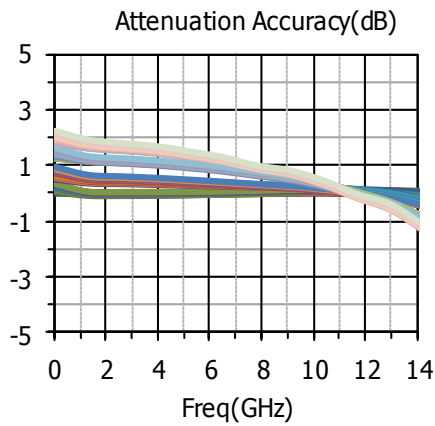


XT3403

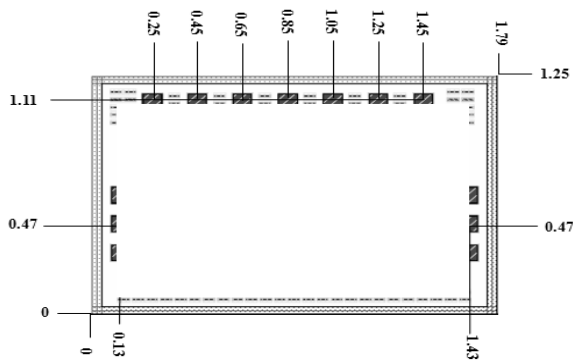


GaAs MMIC Digital Attenuator
8~12GHz

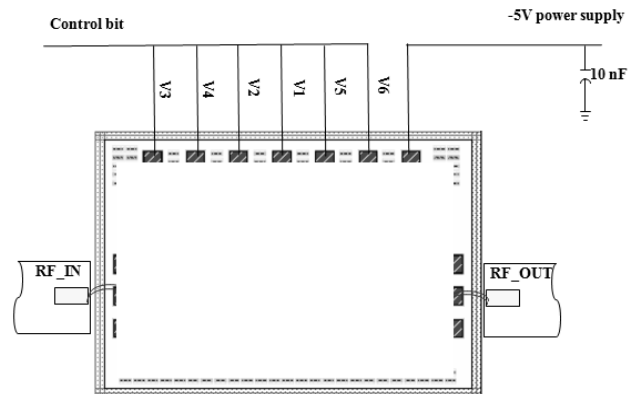
Rev 2.0



Die Outline
(all dimensions in mm)



Assembly Diagram



Attention:

GaAs MMIC devices are susceptible to damage from electrostatic discharge. Proper precautions should be observed during handling, assembly and test.